TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

# T A 8 O 8 3 F

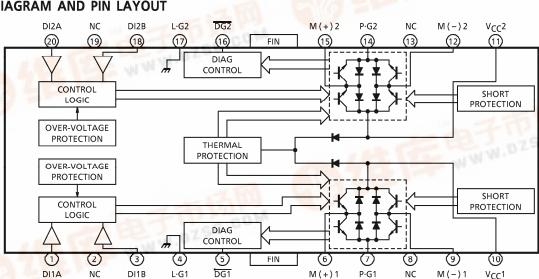
# **DUAL DC MOTOR DRIVER**

The TA8083F contains two motor driver circuits with a current capacity of 0.5A for directly driving bidirectional DC motors. Inputs DI1 A/B and DI2 A/B are combined to select one of forward, reverse Stop, and brake modes. Since the inputs are TTL-Compatible, this IC can be controlled directly from a CPU or other control system. In addition, the IC also has a low stand by current function, a self-diagnostic function, and various protective functions.

#### **FEATURES**

- 0.5A bidirectional DC motor driver.
- Two circuits contained (power supply, self-diagnostic, and protective functions provide for each channel)
- Low standby current : 0.1mA (Max.)
- Self-diagnostic output: short-circuit mode (1A Typ.)
- Protective functions : Thermal-Shutdown, Short-Circuit Protection, and Over-voltage Shutdown WWW.DZSC.GOM
- Built-in counter electromotive force absorption diodes.
- HSOP 20pin power flat package.

#### **BLOCK DIAGRAM AND PIN LAYOUT**

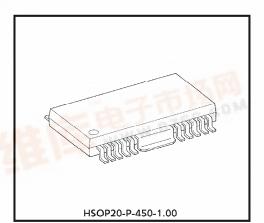


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Weight: 0.79g (Typ.)

# PIN DESCRIPTION

PIN No.		BOL	DESCRIPTION		
CH2	CH1	CH2			
20	DI1A	DI2A	Input pin. The signal from this pin controls the output state.		
18	DI1B	DI2B	(see TRUTH TABLE 1.)		
17	L∙G1	L·G2	Ground terminal for Logic portion.		
16	DG1	DG2	Self-diagnosis output pins (See Table 2, Truth Table & Timing Chart.) NPN transistor open-collector output. When output becomes overcurrent, set to on; duty 97% on (low). At normal operation or at the time of STOP, set to open (high).		
15	M (+)1	M(+)2	Connects to the DC motor. Both the sink and the source have a current capacity of 0.5A. Features overcurrent detection function to protect IC from instantaneous destruction at load short, ground fault, or direct connection to hihg power. (See section on Multiple Protections below.) Features diodes for absorbing counter electromotive force built into both VCC and Gnd sides.		
14	P·G1	P∙G2	Ground terminal for output portion.		
12	M ( – ) 1	M (-)2	Connects to the motor for CH1 (CH2) together with pin 6 (15) and has the same function as pin 6 (15). This pin is controlled by the inputs from pins 1 (20) and 3 (18).		
11	V <sub>CC</sub> 1	V <sub>CC</sub> <sup>2</sup>	Power supply pin. This pin has a function to turn off the output when the applied voltage exceeds 30V, thus protecting the IC and the motor load.  Not connected.		
	20 18 17 16 15	20 DI1A 18 DI1B 17 L·G1  16 DG1  15 M(+)1  14 P·G1  12 M(-)1	20 DI1A DI2A  18 DI1B DI2B  17 L·G1 L·G2  16 DG1 DG2  15 M(+) 1 M(+) 2  14 P·G1 P·G2  12 M(-) 1 M(-) 2		

## TRUTH TABLE 1 INPUT/OUTPUT

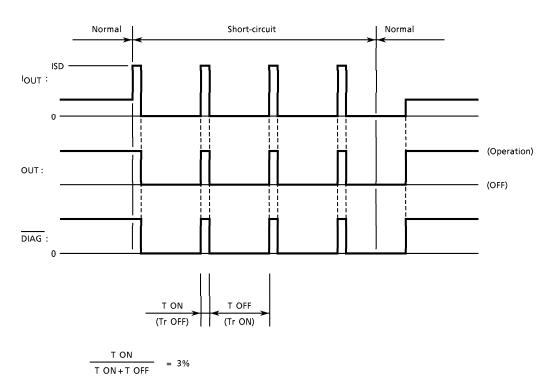
INPUT		OUT	PUT	OPERATION MODE	
DI1/2A	DI1 / 2B	M1(+)/2(+)	M1(-)/2(-)	OPERATION MIDDE	
Н	Н	L	L	Brake	
L	Н	L	Н	Reverse (CCW)	
Н	L	Н	L	Forward (CW)	
L	L	OFF (High	impedance)	Stop (standby)	

# TRUTH TABLE 2 SELF-DIAGNOSIS

INPUT		OUTPUT		DIAG	
DI1/2A	DI1 / 2B	MODE	LOAD	DIAG	
Н	н	Brake	Normal	Н	
			Short	L*	
L/H	H/L	ccw/cw	Normal	Н	
			Short	L*	
L	L	Stop	_	Н	

<sup>\*</sup> See TIMING CHART

# **SELF-DIAGNOSIS TIMIGN CHART**

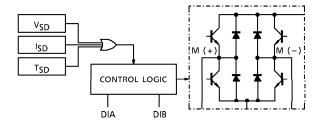


#### **DESCRIPTION OF MULTI-PROTECTIVE OPERATION**

The TA8083F has functions for protection from over-voltage ( $V_{SD}$ ), over-current ( $I_{SD}$ ), and overheat ( $I_{SD}$ ). These functions protect the IC (and the motor load in some cases) from deterioration or destruction due to power-related overstress.

The three functions work independently.

Each function is explained below.



## 1. Over-voltage protection (VSD)

#### • Basic operation

When the voltage supplied to the  $V_{CC}$  pin is up to the  $V_{SD}$  detection voltage, the output is controlled by the input signals. However, when the  $V_{CC}$  voltage exceeds the detection voltage, the output enters high-impedance state regardless of the input signals.

#### Detailed explanation

The  $V_{SD}$  voltage is detected by comparing the Zener voltage with the voltage obtained by dividing  $V_{CC}$  with a resistor. When the center voltage of the resistor is higher than the Zener voltage, a transistor-off instruction is issued to the control logic. When it is lower than the Zener voltage, the logic is controlled by the input signals from DIA and DIB.

#### 2. Overheat protection (TSD)

#### • Basic operation

When the junction (chip) temperature is up to the T<sub>SD</sub> detection temperature, the output is controlled by the input signals. When it exceeds the T<sub>SD</sub> detection temperature, the output enters high-impedance state regardless of the input signals.

# Detailed explanation

The temperature is detected by monitoring  $V_F$  of a diode on the chip. When the diode  $V_F$  is lower than the internal reference voltage, an output transistor-off instruction is issued to the control logic. When it is higher than the internal reference voltage, the logic is controlled by the input signals from DIA and DIB.

# 3. Over-current protection (ISD)

#### Basic operation

When the output current (M (+) or M (-), Isink or Isource) is up to the I<sub>SD</sub> detection current, the output is controlled by the input signals. When it exceeds the detection current, the output assumes a switching waveform as shown in Fig.1.

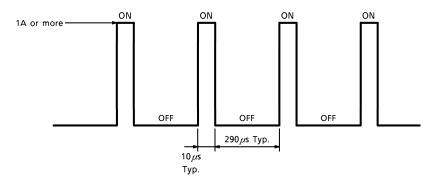


Fig.1 Basic Operation

#### • Detailed explanation

The output current is detected by monitoring the sense resistance. One detection circuit connects to one of the circuits (CH1 or CH2) and leads to the short-circuit protection circuit. When a current exceeding the  $I_{SD}$  detection current flows through one of the four output transistors, the short-circuit protection circuit is activated. This circuit contains a timer. When over-current condition continues for  $10\mu s$  (typically), the protection circuit places the output in high-impedance mode and,  $290\mu s$  (typically) later, returns the IC to ON mode. The switching-waveform output is repeated until over-current condition is no longer present.

## • Caution for application

The overcurrent protection is used to protect the IC from instantaneous destruction due to short circuits. If overcurrent continues, configure a system which changes the IC to standby mode using the self diagnosis signal.

Note that the time required for switching the IC from output short (overcurrent detection) to standby must be 1s or less.

# **MAXIMUM RATINGS** (Ta = $25^{\circ}$ C)

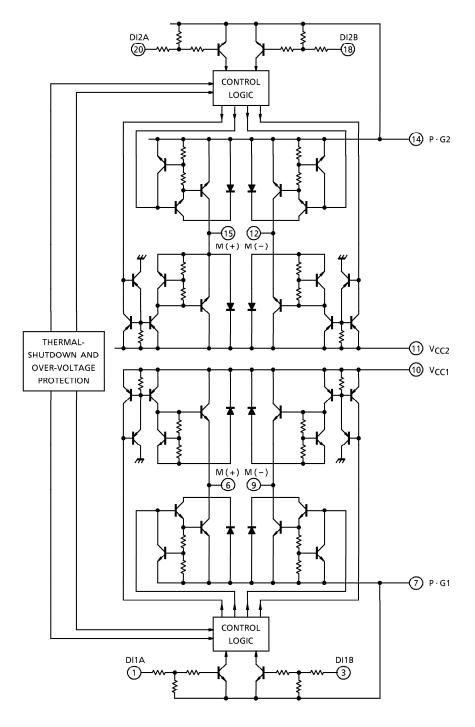
CHARACTERISTIC	SYMBOL	RATING	UNIT	
Power Supply Voltage	V <sub>CC</sub>	30 60 (1s)	٧	
Input Voltage	VIN	-0.3V~V <sub>CC</sub> +0.3	V	
Output Current	IO·AVE	0.5	Α	1
Power Dissipation	PD	2	W	(*)
Operating Temperature	Topr	-40~110	°C	l
Storage Temperature	T <sub>stq</sub>	- 55~150	°C	1
Lead Temperature·Time	T <sub>sol</sub>	260 (10s)	°C	1

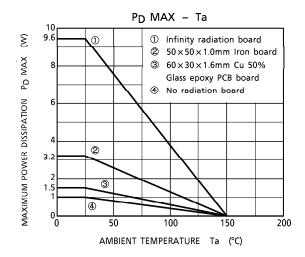
(\*) On Board Condition.  $(50 \times 50 \times 1.6 \text{mm} 50\% \text{ Cu})$ 

# **ELECTRICAL CHARACTERISTICS** ( $V_{CC} = 8 \sim 16V$ , $T_{C} = -40 \sim 110^{\circ}C$ )

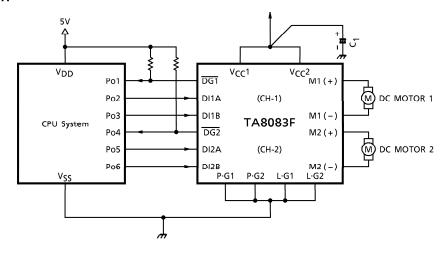
			•					
SYMBOL	PIN	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
I <sub>CC</sub> 1	V <sub>CC</sub> 1/V <sub>CC</sub> 2	_	CH1/CH2: Stop	_	_	0.1		
ICC2		_	CH1 or CH2 : CW/CCW	_	20	30	mA	
ICC3		_	CH1/CH2: CW/CCW	_	40	60		
I <sub>CC</sub> 4		_	CH1/CH2 : Brake		10	16		
٧ <sub>L</sub>		_			_	0.8	V	
$\vee_{IH}$	DI1A/B	_	_	2.0	_	_	· · I	
⊒	DI2A/B	_	$V_{IN} = 0.4V$		10	20	μΑ	
Ή		_	V <sub>IN</sub> = 5V		300	600		
\//+a+a \	M(+)/(-)1/- M(+)/(-)2-	_	I <sub>OUT</sub> = 0.4A, Tc = 25°C	_	1.8	2.5	· ν · μΑ	
		_	I <sub>OUT</sub> = 0.4A, Tc = 110°C	_	1.7	2.4		
<sup>I</sup> LEAK∙U		_	V <sub>OUT</sub> = 0V	<b>– 10</b>	_			
		_	V <sub>OUT</sub> = V <sub>CC</sub>	_	_	10		
V <sub>F</sub> U		_	15 - 0.40	_	1.5	<b>—</b>	V	
V <sub>F</sub> L		_	1F = 0.4A	_	1.5	_		
V <sub>OL</sub>	DG1/DG2	_	I <sub>OL</sub> = 3mA	l	_	0.5	٧	
ILEAK	DG17 DG2	_	V <sub>OUT</sub> = V <sub>CC</sub>		_	10	$\mu$ A	
ISD	_	_	_	_	1.0	_	Α	
T <sub>SD</sub>	_	_	ON→OFF	_	150	_	°C	
V <sub>SD</sub>	_	_	_	_	30	_	٧	
T <sub>PLH</sub>	_	_	_	_	1	10	c	
T <sub>PHL</sub>		_	_		1	10	$\mu$ \$	
	SYMBOL  ICC1 ICC2 ICC3 ICC4  VIL  VIH IIL IIH  Vsat (total)  ILEAK·U ILEAK·L  VF U  VF L  VOL  ILEAK  ISD  TSD  VSD  TPLH	SYMBOL         PIN           ICC1 ICC2 ICC3 ICC4         VCC1/VCC2           VIL VIH ILL         DI1A/B DI2A/B           IIH         M(+)/(-)1/M(+)/(-)2           VF U VF L         M(+)/(-)2           VOL ILEAK         DG1/DG2           ILEAK         ISD           TSD         —           VSD         —           TPLH         —	SYMBOL         PIN         TEST CIR-CUIT           ICC1 ICC2 ICC3 ICC4         ————————————————————————————————————	CUIT     CC2	SYMBOL         PIN         TEST CUIT         TEST CONDITION         MIN.           ICC1 ICC2 ICC3 ICC4         ACC1/VCC2 ICC3 ICC4         CH1 or CH2 : CW/CCW         —           VIL VIH VIH IIH         DI1A/B DI2A/B         —         CH1/CH2 : Brake         —           VIH IIH         —         —         —         —           Vsat (total) Vsat (total)         —         —         —         —         —           VF U         VF U         — <td< td=""><td>SYMBOL         PIN         TEST CONDITION CUIT         MIN.         TYP.           ICC1 ICC2 ICC3 ICC3 ICC4         VCC1/VCC2         — CH1/CH2 : Stop — 20         — CH1/CH2 : CW/CCW — 40           VIL VIL VIH VIH IIL         DI1A/B DI2A/B         — CH1/CH2 : Brake — 10         — — — 2.0           VIH VIH VIH VIH VIH VIH VIH VIH VIH VIH</td><td>SYMBOL         PIN         TEST CIR CILT         TEST CONDITION         MIN.         TYP.         MAX.           ICC1 ICC2 ICC3 ICC3 ICC4         VCC1/VCC2 ICC3 ICC4         — CH1/CH2: Stop         — 20 30           VIL VIH VIH IIL         DI1A/B DI2A/B         — CH1/CH2: CW/CCW         — 40 60           VIH VIH IIL         DI1A/B DI2A/B         — CH1/CH2: Brake         — 10 16           Vyat (total)         — VIN=0.4V         — 10 20           Vsat (total)         — VIN=5V         — 300 600           Vsat (total)         M(+)/(-)1/M(+)/(-)2         — IOUT=0.4A, Tc=25°C         — 1.8 2.5           — VOUT=0.4A, Tc=110°C         — 1.7 2.4         — VOUT=0.4A, Tc=110°C         — 1.5 —           VF U         VF U         — VOUT=0.4A, Tc=110°C         — 1.5 —         — 10           VF U         VF U         — IF=0.4A         — 1.5 —         — 10           VOL         — DG1/DG2         — IOL=3mA         — 1.5 —         — 10           ILEAK         — VOUT=VCC         — 1.0 —         — 1.5         — 10           ISD         — ON→OFF         — 1.0 —         — 1.0         — 1.0           VSD         — ON→OFF         — 30         — 1.0           TPLH         — ON→OFF         — 10         — 1</td></td<>	SYMBOL         PIN         TEST CONDITION CUIT         MIN.         TYP.           ICC1 ICC2 ICC3 ICC3 ICC4         VCC1/VCC2         — CH1/CH2 : Stop — 20         — CH1/CH2 : CW/CCW — 40           VIL VIL VIH VIH IIL         DI1A/B DI2A/B         — CH1/CH2 : Brake — 10         — — — 2.0           VIH	SYMBOL         PIN         TEST CIR CILT         TEST CONDITION         MIN.         TYP.         MAX.           ICC1 ICC2 ICC3 ICC3 ICC4         VCC1/VCC2 ICC3 ICC4         — CH1/CH2: Stop         — 20 30           VIL VIH VIH IIL         DI1A/B DI2A/B         — CH1/CH2: CW/CCW         — 40 60           VIH VIH IIL         DI1A/B DI2A/B         — CH1/CH2: Brake         — 10 16           Vyat (total)         — VIN=0.4V         — 10 20           Vsat (total)         — VIN=5V         — 300 600           Vsat (total)         M(+)/(-)1/M(+)/(-)2         — IOUT=0.4A, Tc=25°C         — 1.8 2.5           — VOUT=0.4A, Tc=110°C         — 1.7 2.4         — VOUT=0.4A, Tc=110°C         — 1.5 —           VF U         VF U         — VOUT=0.4A, Tc=110°C         — 1.5 —         — 10           VF U         VF U         — IF=0.4A         — 1.5 —         — 10           VOL         — DG1/DG2         — IOL=3mA         — 1.5 —         — 10           ILEAK         — VOUT=VCC         — 1.0 —         — 1.5         — 10           ISD         — ON→OFF         — 1.0 —         — 1.0         — 1.0           VSD         — ON→OFF         — 30         — 1.0           TPLH         — ON→OFF         — 10         — 1	

# I/O EQUIVALENT CIRCUIT





## **APPLICATION CIRCUIT**



Cautions for wirings C<sub>1</sub> is for absorbing disturbance, noise, etc. Connect it as close to the IC as possible.

# **OUTLINE DRAWING** HSOP20-P-450-1.00 Unit: mm 4.4±0.1 8.8±0.2 12.0±0.3 HHH $\mathbb{H}$ 10 1.0 0.5±0.1 1.0TYP 3.0 16.5MAX 16.0±0.2 0.25 +0.1 0.92±0.2

Weight: 0.79g (Typ.)